

FEATURES

- 1.3 pF off capacitance
- 3.5 pF on capacitance
- 1 pC charge injection
- 33 V supply range
- 120 Ω on resistance
- Fully specified at +12 V, ± 15 V
- No V_L supply required
- 3 V logic-compatible inputs
- Rail-to-rail operation
- 16-lead TSSOP and 12-lead LFCSP packages
- Typical power consumption: <0.03 μ W

APPLICATIONS

- Automatic test equipment
- Data acquisition systems
- Battery-powered systems
- Sample-and-hold systems
- Audio/video signal routing
- Communication systems

GENERAL DESCRIPTION

The **ADG1236** is a monolithic CMOS device containing two independently selectable SPDT switches. It is designed on an *i*CMOS® process. *i*CMOS (industrial CMOS) is a modular manufacturing process combining high voltage complementary metal-oxide semiconductor (CMOS) and bipolar technologies. It enables the development of a wide range of high performance analog ICs capable of 33 V operation in a footprint that no previous generation of high voltage devices has been able to achieve. Unlike analog ICs using conventional CMOS processes, *i*CMOS components can tolerate high supply voltages while providing increased performance, dramatically lower power consumption, and reduced package size.

The ultralow capacitance and charge injection of the device make it an ideal solution for data acquisition and sample-and-hold applications, where low glitch and fast settling are required. Fast switching speed coupled with high signal bandwidth makes the device suitable for video signal switching. *i*CMOS construction ensures ultralow power dissipation, making the device ideally suited for portable and battery-powered instruments.

FUNCTIONAL BLOCK DIAGRAM

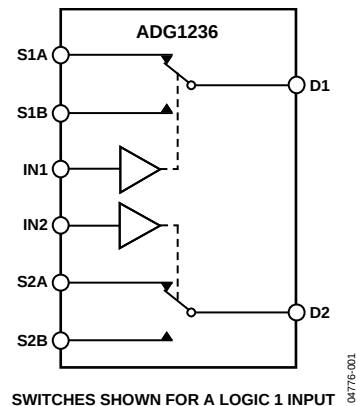


Figure 1.

Each switch conducts equally well in both directions when on and has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked. Both switches exhibit break-before-make switching action for use in multiplexer applications.

PRODUCT HIGHLIGHTS

1. 1.3 pF off capacitance (± 15 V supply).
2. 1 pC charge injection.
3. 3 V logic-compatible digital inputs: $V_{IH} = 2.0$ V, $V_{IL} = 0.8$ V.
4. No V_L logic power supply required.
5. Ultralow power dissipation: <0.03 μ W.
6. 16-lead TSSOP and 12-lead 3 mm $\times$ 3 mm LFCSP packages.

ADG1236* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- Evaluation Board for 16 lead TSSOP Devices in the Switch/Mux Portfolio

DOCUMENTATION

Application Notes

- AN-874: Operating the ADG12xx Series of Parts with 5 V Supplies and the Impact on Performance

Data Sheet

- ADG1236: Low Capacitance, Low Charge Injection, ± 15 V/12 V CMOS, Dual SPDT Switch Data Sheet

User Guides

- UG-945: Evaluation Board for 16-Lead TSSOP Devices in the Switches and Multiplexers Portfolio

TOOLS AND SIMULATIONS

- ADG1236 SPICE Macro Model

REFERENCE MATERIALS

Product Selection Guide

- Switches and Multiplexers Product Selection Guide

Technical Articles

- CMOS Switches Offer High Performance in Low Power, Wideband Applications
- Data-acquisition system uses fault protection

DESIGN RESOURCES

- ADG1236 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all ADG1236 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

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REVISION HISTORY

3/16—Rev. 0 to Rev. A	
Changes to Figure 2 and Figure 3	7
Updated Outline Dimensions	14
Changes to Ordering Guide	14

9/05—Revision 0: Initial Version

SPECIFICATIONS

DUAL SUPPLY

$V_{DD} = 15\text{ V} \pm 10\%$, $V_{SS} = -15\text{ V} \pm 10\%$, GND = 0 V, unless otherwise noted.

Table 1.

Parameters	Y Version ¹			Unit	Test Conditions/Comments ¹
	25°C	−40°C to +85°C	−40°C to +125°C		
ANALOG SWITCH					
Analog Signal Range			V _{DD} to V _{SS}	V	V _S = ±10 V, I _S = −1 mA; Figure 20 V _{DD} = +13.5 V, V _{SS} = −13.5 V V _S = ±10 V, I _S = −1 mA
On Resistance (R _{ON})	120			Ω typ	
	190	230	260	Ω max	
On Resistance Match Between Channels (ΔR _{ON})	3.5			Ω typ	
	6	10	12	Ω max	V _S = −5 V, 0 V, +5 V; I _S = −1 mA
On Resistance Flatness (R _{FLAT(ON)})	20			Ω typ	
	57	72	79	Ω max	
LEAKAGE CURRENTS					
Source Off Leakage, I _S (Off)	±0.02			nA typ	V _{DD} = +16.5 V, V _{SS} = −16.5 V V _S = ±10 V, V _S = ∓10 V; Figure 21
	±0.1	±0.6	±1	nA max	V _S = ±10 V, V _S = ∓10 V; Figure 21
Drain Off Leakage, I _D (Off)	±0.02			nA typ	
	±0.1	±0.6	±1	nA max	
Channel On Leakage, I _D , I _S (On)	±0.02			nA typ	V _S = V _D = ±10 V; Figure 22
	±0.2	±0.6	±1	nA max	
DIGITAL INPUTS					
Input High Voltage, V _{INH}			2.0	V min	V _{IN} = V _{INL} or V _{INH}
Input Low Voltage, V _{INL}			0.8	V max	
Input Current, I _{INL} or I _{INH}	0.005			μA typ	
			±0.1	μA max	
Digital Input Capacitance, C _{IN}	2			pF typ	
DYNAMIC CHARACTERISTICS ²					
Transition Time, t _{TRANS AOFF BON}	125			ns typ	R _L = 300 Ω, C _L = 35 pF
	150		200	ns max	V _S = 10 V; Figure 23
Transition Time, t _{TRANS BOFF AON}	70			ns typ	R _L = 300 Ω, C _L = 35 pF
	90		115	ns max	V _S = 10 V; Figure 23
Break-Before-Make Time Delay, t _D	25			ns typ	R _L = 300 Ω, C _L = 35 pF
			10	ns min	V _{S1} = V _{S2} = 10 V; Figure 24
Charge Injection	−1			pC typ	V _S = 0 V, R _S = 0 Ω, C _L = 1 nF; Figure 25
Off Isolation	80			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; Figure 26
Channel-to-Channel Crosstalk	85			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; Figure 27
Total Harmonic Distortion + Noise	0.15			% typ	R _L = 10 kΩ, 5 V rms, f = 20 Hz to 20 kHz
−3 dB Bandwidth	1000			MHz typ	R _L = 50 Ω, C _L = 5 pF; Figure 28
C _S (Off)	1.3			pF typ	f = 1 MHz; V _S = 0 V
	1.6			pF max	f = 1 MHz; V _S = 0 V
C _D , C _S (On)	3.5			pF typ	f = 1 MHz; V _S = 0 V
	4.3			pF max	f = 1 MHz; V _S = 0 V

Parameters	Y Version ¹			Unit	Test Conditions/Comments ¹
	25°C	–40°C to +85°C	–40°C to +125°C		
POWER REQUIREMENTS					$V_{DD} = +16.5\text{ V}$, $V_{SS} = -16.5\text{ V}$
I_{DD}	0.001		1.0	$\mu\text{A typ}$ $\mu\text{A max}$	Digital inputs = 0 V or V_{DD}
I_{DD}	170		230	$\mu\text{A typ}$ $\mu\text{A max}$	Digital inputs = 5 V
I_{SS}	0.001		1.0	$\mu\text{A typ}$ $\mu\text{A max}$	Digital inputs = 0 V or V_{DD}
I_{SS}	0.001		1.0	$\mu\text{A typ}$ $\mu\text{A max}$	Digital inputs = 5 V

¹ Temperature range for Y version is –40°C to +125°C.

² Guaranteed by design; not subject to production test.

SINGLE SUPPLY

$V_{DD} = 12\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.

Table 2.

Parameters	Y Version ¹			Unit	Test Conditions/Comments
	25°C	–40°C to +85°C	–40°C to +125°C		
ANALOG SWITCH					
Analog Signal Range			0 V to V _{DD}	V	
On Resistance (R _{ON})	300			Ω typ	V _S = 0 V to 10 V, I _S = –1 mA; Figure 20
	475	567	625	Ω max	V _{DD} = 10.8 V, V _{SS} = 0 V
On Resistance Match Between Channels (ΔR _{ON})	4.5			Ω typ	V _S = 0 V to 10 V, I _S = –1 mA
	16	26	27	Ω max	
On Resistance Flatness (R _{FLAT(ON)})	60			Ω typ	V _S = 3 V, 6 V, 9 V, I _S = –1 mA
LEAKAGE CURRENTS					
Source Off Leakage, I _S (Off)	±0.02			nA typ	V _{DD} = 13.2 V
	±0.1	±0.6	±1	nA max	V _S = 1 V/10 V, V _D = 10 V/1 V; Figure 21
Drain Off Leakage, I _D (Off)	±0.02			nA typ	V _S = 1 V/10 V, V _D = 10 V/1 V; Figure 21
	±0.1	±0.6	±1	nA max	
Channel On Leakage, I _D , I _S (On)	±0.02			nA typ	V _S = V _D = 1 V or 10 V, Figure 22
	±0.2	±0.6	±1	nA max	
DIGITAL INPUTS					
Input High Voltage, V _{INH}			2.0	V min	
Input Low Voltage, V _{INL}			0.8	V max	
Input Current, I _{INL} or I _{INH}	0.001			μA typ	V _{IN} = V _{INL} or V _{INH}
			±0.1	μA max	
Digital Input Capacitance, C _{IN}	3			pF typ	
DYNAMIC CHARACTERISTICS ²					
Transition Time, t _{TRANS B_{OFF} A_{ON}}	105			ns typ	R _L = 300 Ω, C _L = 35 pF
	140		175	ns max	V _S = 8 V; Figure 23
Transition Time, t _{TRANS A_{OFF} B_{ON}}	155			ns typ	R _L = 300 Ω, C _L = 35 pF
	190		255	ns max	V _S = 8 V; Figure 23
Break-Before-Make Time Delay, t _D	50			ns typ	R _L = 300 Ω, C _L = 35 pF
			10	ns min	V _{S1} = V _{S2} = 8 V; Figure 24
Charge Injection	–0.8			pC typ	V _S = 6 V, R _S = 0 Ω, C _L = 1 nF; Figure 25
Off Isolation	75			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; Figure 26;
Channel-to-Channel Crosstalk	85			dB typ	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz; Figure 27
–3 dB Bandwidth	800			MHz typ	R _L = 50 Ω, C _L = 5 pF; Figure 28
C _S (Off)	1.6			pF typ	f = 1 MHz; V _S = 6 V
	1.9			pF max	f = 1 MHz; V _S = 6 V
C _D , C _S (On)	4			pF typ	f = 1 MHz; V _S = 6 V
	4.9			pF max	f = 1 MHz; V _S = 6 V
POWER REQUIREMENTS					
I _{DD}	0.001			μA typ	V _{DD} = 13.2 V
			1.0	μA max	Digital inputs = 0 V or V _{DD}
I _{DD}	170			μA typ	Digital inputs = 5 V
			230	μA max	

¹ Temperature range for Y version is –40°C to +125°C.

² Guaranteed by design; not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 3.

Parameter	Rating
V_{DD} to V_{SS}	35 V
V_{DD} to GND	–0.3 V to +25 V
V_{SS} to GND	+0.3 V to –25 V
Analog Inputs ¹	$V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first
Digital Inputs ¹	GND – 0.3 V to $V_{DD} + 0.3\text{ V}$ or 30 mA, whichever occurs first
Peak Current, S or D	100 mA (pulsed at 1 ms, 10% duty cycle max)
Continuous Current per Channel, S or D	25 mA
Operating Temperature Range Automotive (Y Version)	–40°C to +125°C
Storage Temperature Range	–65°C to +150°C
Junction Temperature	150°C
16-Lead TSSOP, θ_{JA} Thermal Impedance	112°C/W
12-Lead LFCSP, θ_{JA} Thermal Impedance	80°C/W
Reflow Soldering Peak Temperature, Pb Free	260°C

¹ Over voltages at IN, S, or D are clamped by internal diodes. Current must be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TRUTH TABLE FOR SWITCHES

Table 4.

IN	Switch A	Switch B
0	Off	On
1	On	Off

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

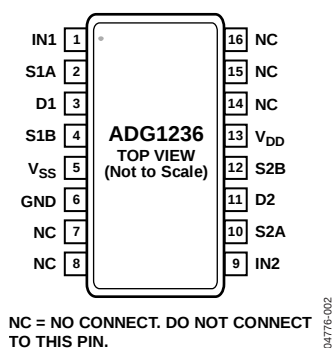


Figure 2. TSSOP Pin Configuration

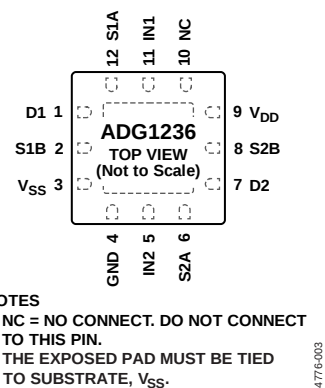


Figure 3. LFCSP Pin Configuration

Table 5. Pin Function Descriptions

Pin No.		Mnemonic	Description
TSSOP	LFCSP		
1	11	IN1	Logic Control Input.
2	12	S1A	Source Terminal. Can be an input or output.
3	1	D1	Drain Terminal. Can be an input or output.
4	2	S1B	Source Terminal. Can be an input or output.
5	3	V_{SS}	Most Negative Power Supply Potential.
6	4	GND	Ground (0 V) Reference.
7, 8, 14 to 16	10	NC	No Connect.
9	5	IN2	Logic Control Input.
10	6	S2A	Source Terminal. Can be an input or output.
11	7	D2	Drain Terminal. Can be an input or output.
12	8	S2B	Source Terminal. Can be an input or output.
13	9	V_{DD}	Most Positive Power Supply Potential.

TERMINOLOGY

I_{DD}

The positive supply current.

I_{SS}

The negative supply current.

V_D (V_S)

The analog voltage on Terminals D and S.

R_{ON}

The ohmic resistance between D and S.

R_{FLAT(ON)}

Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal range.

I_S (Off)

The source leakage current with the switch off.

I_D (Off)

The drain leakage current with the switch off.

I_D, I_S (On)

The channel leakage current with the switch on.

V_{INL}

The maximum input voltage for Logic 0.

V_{INH}

The minimum input voltage for Logic 1.

I_{INL} (I_{INH})

The input current of the digital input.

C_S (Off)

The off switch source capacitance, measured with reference to ground.

C_D (Off)

The off switch drain capacitance, measured with reference to ground.

C_D, C_S (On)

The on switch capacitance, measured with reference to ground.

C_{IN}

The digital input capacitance.

t_{TRANS}

The delay time between the 50% and 90% points of the digital input and switch on condition when switching from one address state to another.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Off Isolation

A measure of unwanted signal coupling through an off switch.

Crosstalk

A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

Bandwidth

The frequency at which the output is attenuated by 3 dB.

On Response

The frequency response of the on switch.

Insertion Loss

The loss due to the on resistance of the switch.

THD + N

The ratio of the harmonic amplitude plus noise of the signal to the fundamental.

TYPICAL PERFORMANCE CHARACTERISTICS

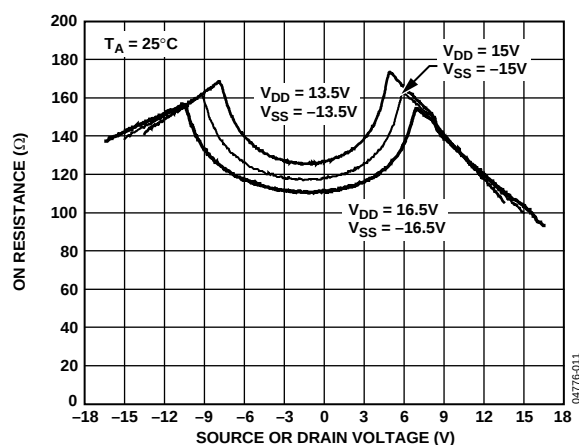
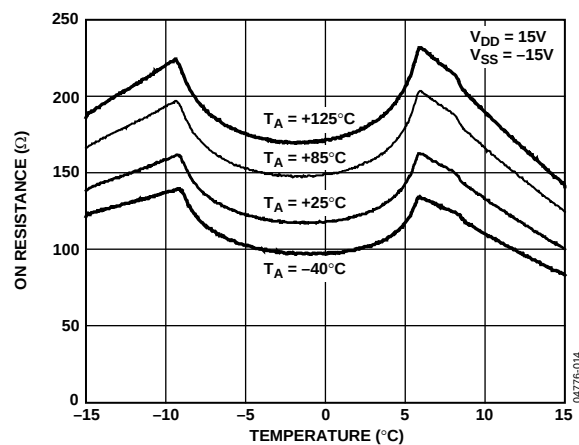
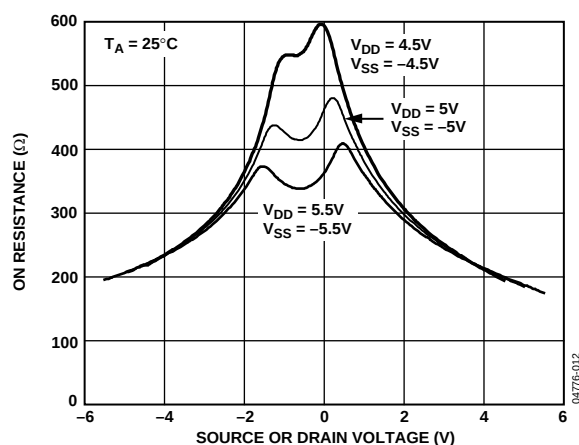
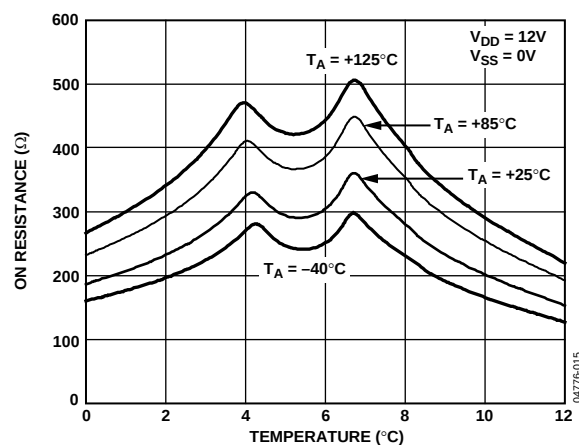
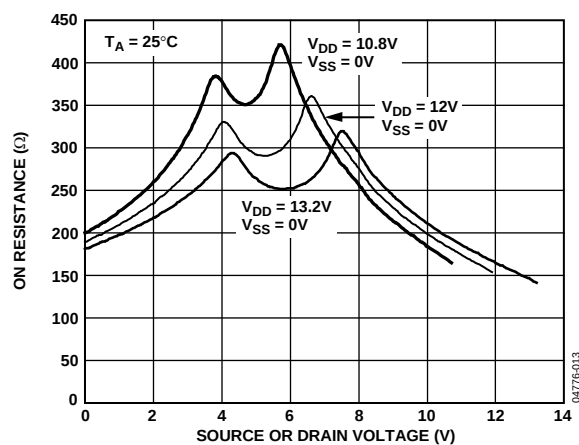
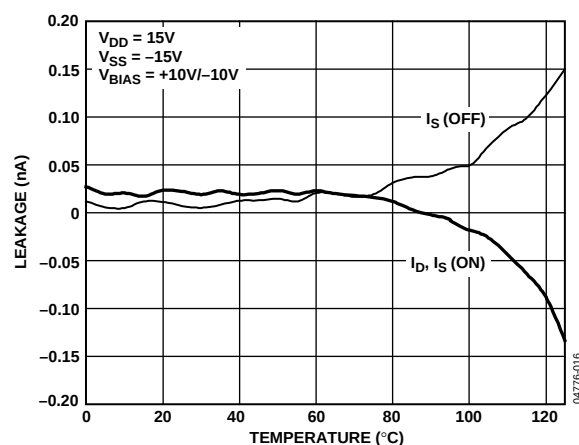
Figure 4. On Resistance as a Function of V_D (V_S) for Dual SupplyFigure 7. On Resistance as a Function of V_D (V_S) for Different Temperatures, Dual SupplyFigure 5. On Resistance as a Function of V_D (V_S) for Dual SupplyFigure 8. On Resistance as a Function of V_D (V_S) for Different Temperatures, Single SupplyFigure 6. On Resistance as a Function of V_D (V_S) for Single Supply

Figure 9. Leakage Currents as a Function of Temperature, Dual Supply

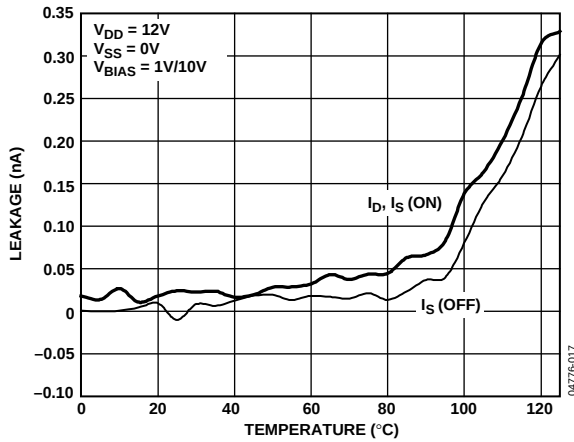


Figure 10. Leakage Currents as a Function of Temperature, Single Supply

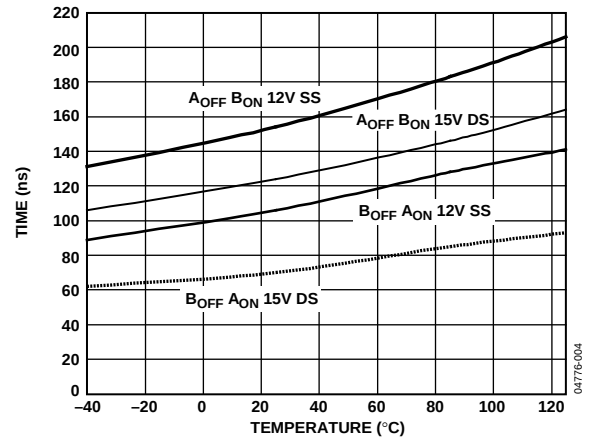


Figure 13. $t_{\text{TRANSITION}}$ Times vs. Temperature

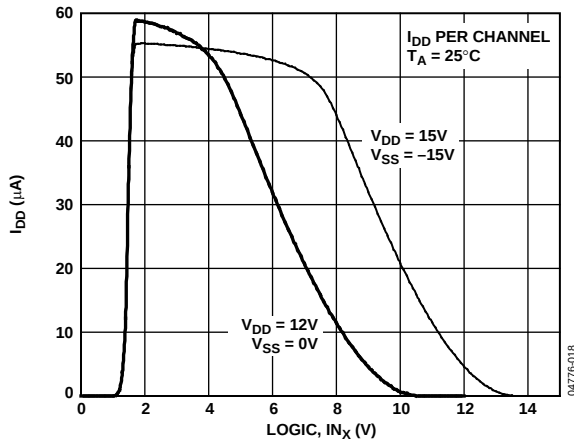


Figure 11. I_{DD} vs. Logic Level

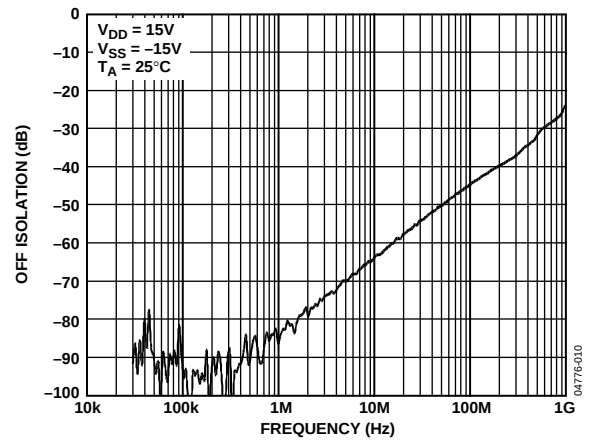


Figure 14. Off Isolation vs. Frequency

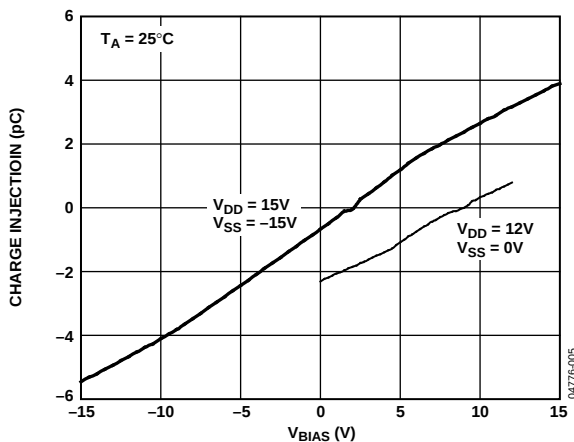


Figure 12. Charge Injection vs. Source Voltage

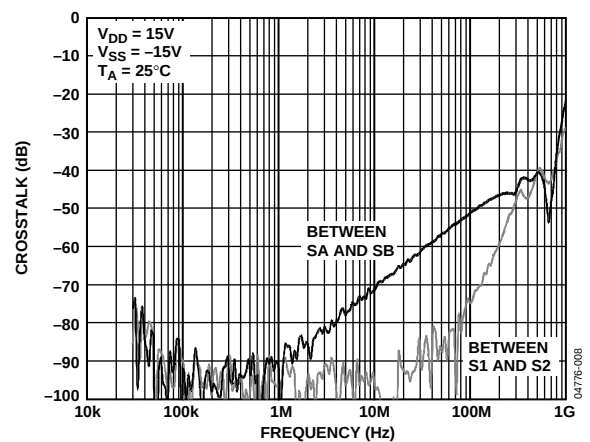


Figure 15. Crosstalk vs. Frequency

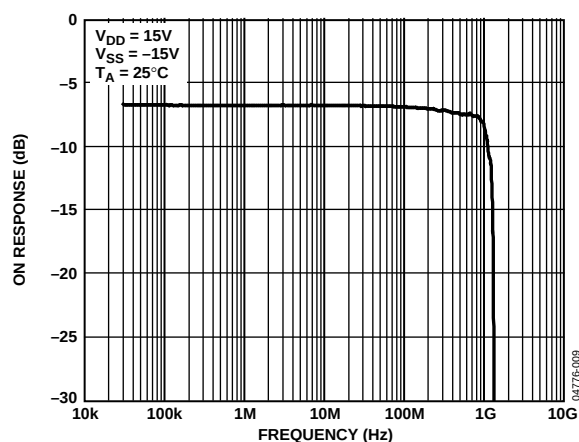


Figure 16. On Response vs. Frequency

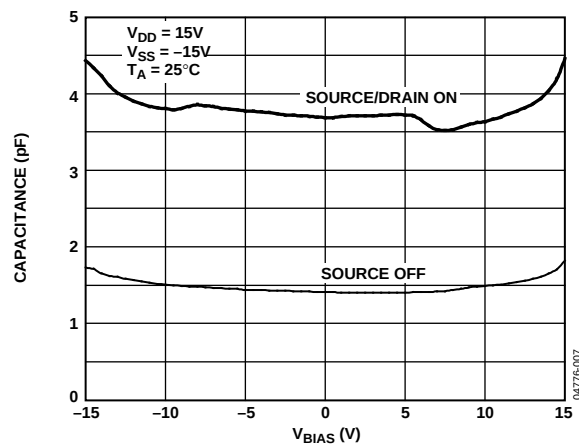


Figure 18. Capacitance vs. Source Voltage for Dual Supply

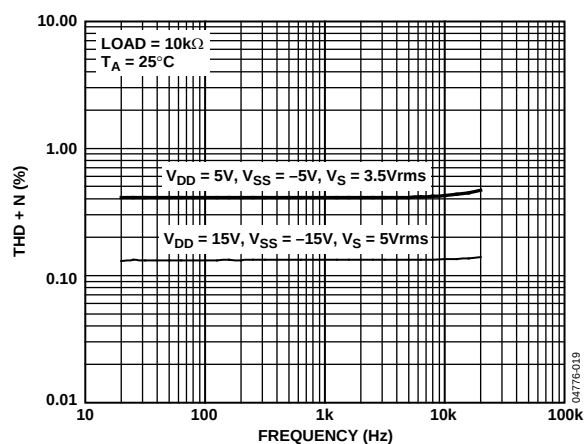


Figure 17. THD + N vs. Frequency

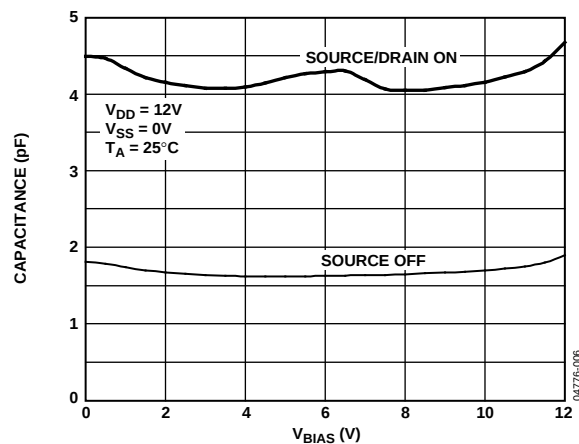


Figure 19. Capacitance vs. Source Voltage for Single Supply

TEST CIRCUITS

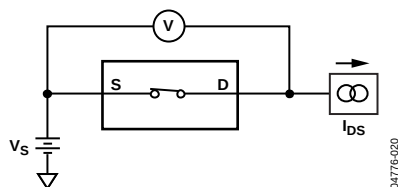


Figure 20. Test Circuit 1—On Resistance

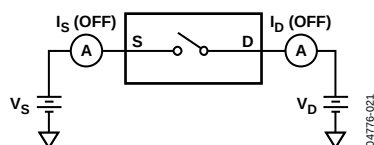


Figure 21. Test Circuit 2—Off Resistance

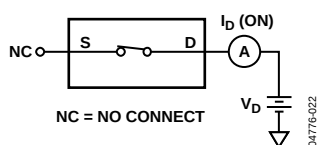


Figure 22. Test Circuit 3—On Leakage

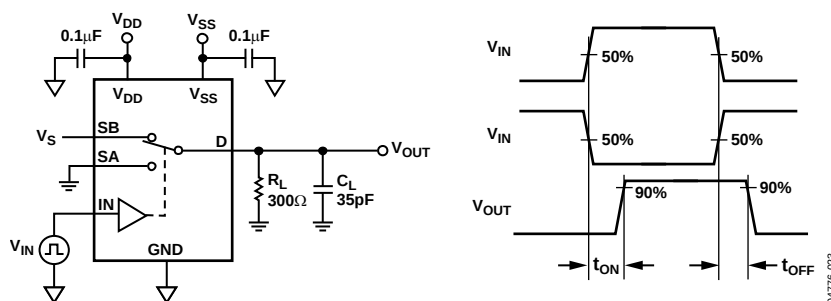


Figure 23. Test Circuit 4—Switching Times

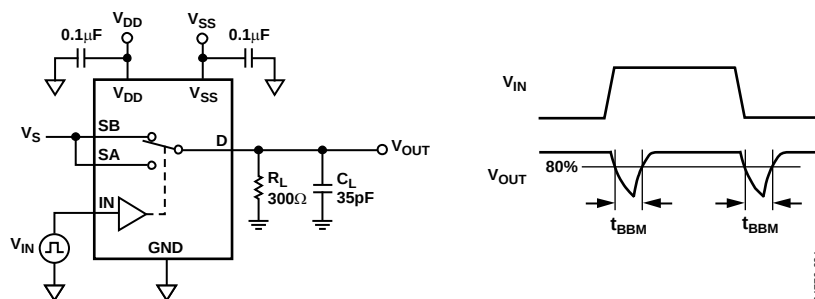


Figure 24. Test Circuit 5—Break-Before-Make Time Delay

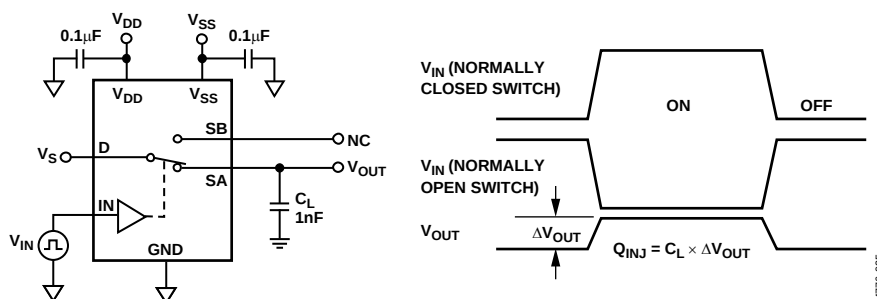


Figure 25. Test Circuit 6—Charge Injection

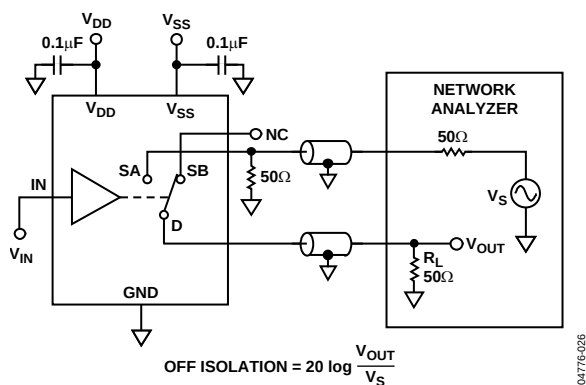


Figure 26. Test Circuit 7—Off Isolation

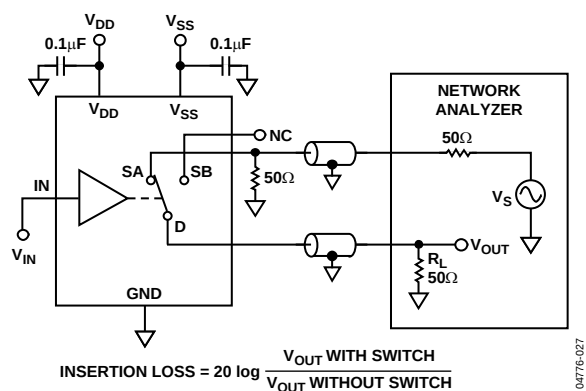


Figure 27. Test Circuit 8—Channel-to-Channel Crosstalk

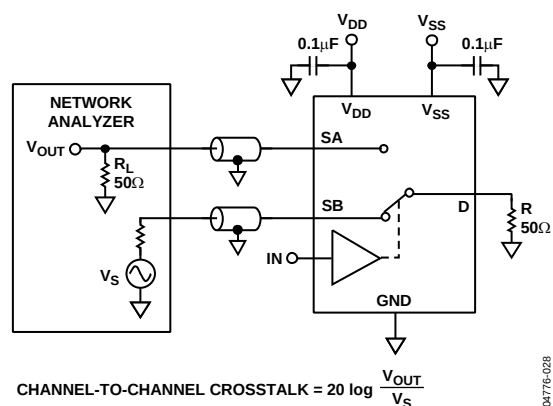


Figure 28. Test Circuit 9—Bandwidth

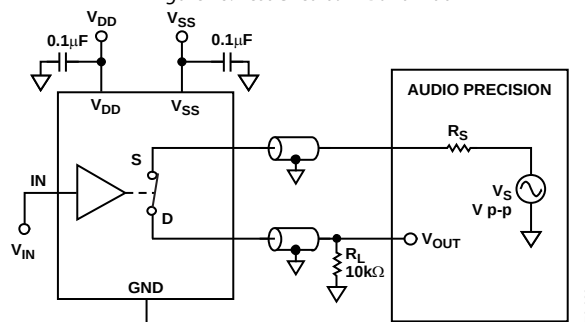


Figure 29. Test Circuit 10—THD + Noise

OUTLINE DIMENSIONS

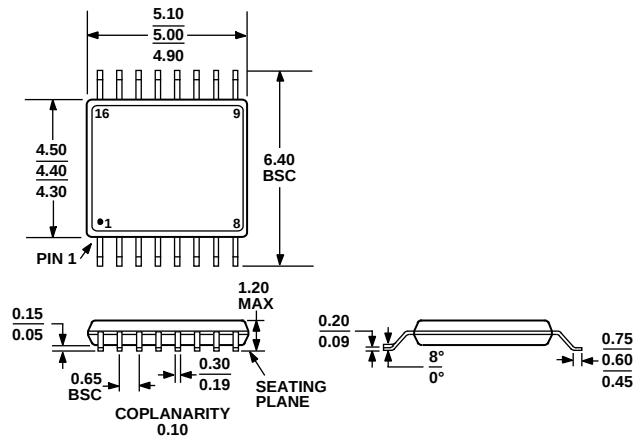


Figure 30. 16-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-16)

Dimensions shown in millimeters

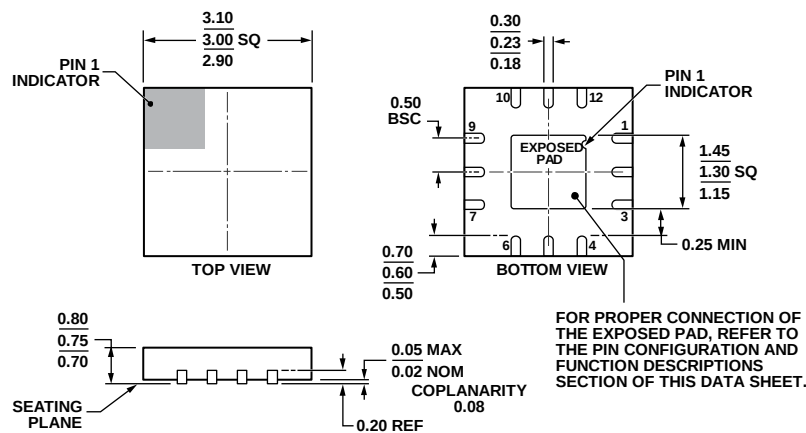


Figure 31. 12-Lead Lead Frame Chip Scale Package [LFCSP]
3 mm × 3 mm Body and 0.75 mm Package Height
(CP-12-4)

Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
ADG1236YRUZ	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1236YRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1236YRUZ-REEL7	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1236YCPZ-500RL7	−40°C to +125°C	12-Lead Lead Frame Chip Scale Package [LFCSP]	CP-12-4
ADG1236YCPZ-REEL7	−40°C to +125°C	12-Lead Lead Frame Chip Scale Package [LFCSP]	CP-12-4

¹ Z = RoHS Compliant Part.

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